ST - 23G

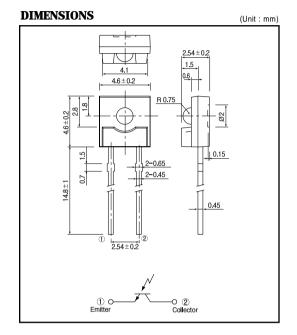
The ST - 23G, a high - sensitivity NPN silicon phototransistor mounted in a clear sidelooking package, is compact, low profile and easy to mount.

FEATURES

- Low profile package
- Compact
- Low cost
- · Sidelooking plastic package

APPLICATIONS

- Photointerrupters
- · Optical switches



MAXIMUM RATINGS

(Ta=25)

| Item | Symbol | Rating | Unit |
|-----------------------------|--------|-------------|------|
| C - E voltage | Vceo | 30 | ٧ |
| E - C voltage | Veco | 6 | V |
| Collector current | lc | 40 | mA |
| Collector power dissipation | Pc | 100 | mW |
| Operating temp. | Topr. | - 20~ + 100 | |
| Storage Temp. | Tstg. | - 30~ + 100 | |
| Soldering temp. '1 | Tsol. | 260 | |

^{*1.} For MAX.5 seconds at the position of 2 mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

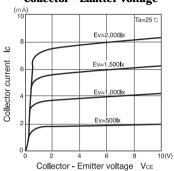
(Ta=25)

| Item | l | Symbol | Conditions | Min. | Тур. | Max. | Unit. |
|----------------------|-----------|----------|----------------------|--------------|------|------|-------|
| Collector dark curr | ent | CEO | Vceo=10V | | 1 | 100 | nA |
| Light current | | L | Vce=5V, 1,000lx *2 | 0.5 | 4.0 | 20 | mA |
| C - E saturation vo | ltage | Vc∈(sat) | Ic=0.5mA, 2,000lx *2 | | 0.2 | 0.4 | V |
| Switching speeds | Rise time | tr | Vcc=10V, lc=5mA, | | 3.2 | | μsec. |
| | Fall time | tf | RL=100 | | 4.8 | | μsec. |
| Spectral sensitivity | | | | 500~1,050 nm | | nm | |
| Peak wavelength | | р | | | 880 | | nm |
| Half anglee | | | | | ± 30 | | deg. |

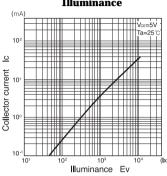
^{*2.} Color temp.=2856K standard Tungsten lamp

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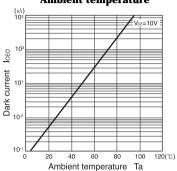
Collector current Vs.
Collector - Emitter voltage



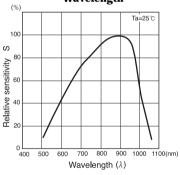
Collector current Vs.
Illuminance



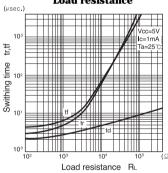
Dark current Vs. Ambient temperature



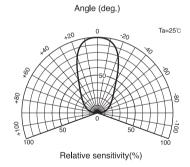
Relative sensitivity Vs. Wavelength



Swithing time vs. Load resistance



Radiant Pattern



Collector power dissipation Vs.
Ambient temperature

